

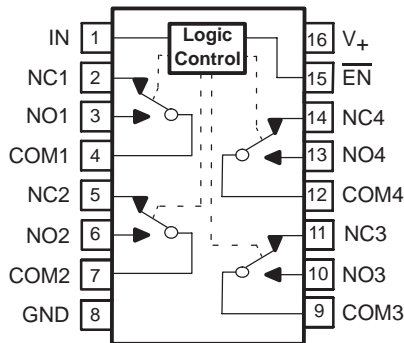
Description

The TS3A5018 is a quad single-pole double-throw (SPDT) analog switch that is designed to operate from 2.3 V to 3.6 V. This device can handle both digital and analog signals, and signals up to V_+ can be transmitted in either direction.

Applications

- Sample-and-Hold Circuit
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits

SOIC, SSOP, TSSOP, OR TVSOP PACKAGE
(TOP VIEW)



FUNCTION TABLE

$\overline{\text{EN}}$	IN	NO TO COM, COM TO NO	NC TO COM, COM TO NC
L	L	OFF	ON
L	H	ON	OFF
H	X	OFF	OFF

Features

- Low ON-State Resistance (10 Ω)
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 2.3-V to 3.6-V Single-Supply Operation
- Control Inputs are 5-V Tolerant
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)

Summary of Characteristics

$V_+ = 3.3 \text{ V}$, $T_A = 25^\circ\text{C}$

Configuration	Quad Single Pole Double Throw (4 × SPDT)
Number of channels	4
ON-state resistance (r_{ON})	7 Ω
ON-state resistance match (Δr_{ON})	0.3 Ω
ON-state resistance flatness ($r_{\text{ON(flat)}}$)	5 Ω
Turn-on/turn-off time ($t_{\text{ON}}/t_{\text{OFF}}$)	3.5 ns/2 ns
Charge injection (Q_C)	2 pC
Bandwidth (BW)	300 MHz
OFF isolation (O_{ISO})	–48 dB at 10 MHz
Crosstalk (X_{TALK})	–48 dB at 10 MHz
Total harmonic distortion (THD)	0.2%
Leakage current ($I_{\text{COM(OFF)}}$)	±5 μA
Power-supply current (I_+)	2.5 μA
Package option	16-pin SOIC, SSOP, TSSOP, or TVSOP



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	SOIC - D	Tube	TS3A5018D	TS3A5018
		Tape and reel	TS3A5018DR	
	SSOP (QSOP) - DBQ	Tape and reel	TS3A5018DBQR	YA018
	TSSOP - PW	Tube	TS3A5018PW	YA018
		Tape and reel	TS3A5018PWR	
	TVSOP - DGV	Tape and reel	TS3A5018DGVR	YA018

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Absolute Minimum and Maximum Ratings⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V ₊	Supply voltage range ⁽³⁾		−0.5	4.6	V
V _{NC} , V _{NO} , V _{COM}	Analog voltage range ⁽³⁾⁽⁴⁾		−0.5	7	V
I _K	Analog port diode current	V _{NC} , V _{NO} , V _{COM} < 0	−50		mA
I _{NC} , I _{NO} , I _{COM}	On-state switch current	V _{NC} , V _{NO} , V _{COM} = 0 to 7 V	−64	64	mA
V _I	Digital input voltage range ⁽³⁾⁽⁴⁾		−0.5	7	V
I _{IK}	Digital input clamp current	V _I < 0	−50		mA
I ₊	Continuous current through V ₊		−100	100	mA
I _{GND}	Continuous current through GND		−100	100	mA
θ _{JA}	Package thermal impedance ⁽⁵⁾	D package		73	°C/W
		DBQ package		90	
		DGV package		120	
		PW package		108	
T _{stg}	Storage temperature range		−65	150	°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(3) All voltages are with respect to ground, unless otherwise specified.

(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(5) The package thermal impedance is calculated in accordance with JESD 51-7.

Electrical Characteristics for 3.3-V Supply⁽¹⁾

$V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NC} , V _{NO}					0		V ₊	V
ON-state resistance	r _{on}	0 ≤ (V _{NC} or V _{NO}) ≤ V ₊ , I _{COM} = −32 mA,	Switch ON, See Figure 13	25°C Full	3 V	7 12		10	Ω
ON-state resistance match between channels	Δr _{on}	V _{NC} or V _{NO} = 2.1 V, I _{COM} = −32 mA,	Switch ON, See Figure 13	25°C Full	3 V	0.3		0.8 1	Ω
ON-state resistance flatness	r _{on(flat)}	0 ≤ (V _{NC} or V _{NO}) ≤ V ₊ , I _{COM} = −32 mA,	Switch ON, See Figure 13	25°C Full	3 V	5		7 8	Ω
NC, NO OFF leakage current	I _{NC(OFF)} I _{NO(OFF)}	V _{NC} or V _{NO} = 1 V, V _{COM} = 3 V, or V _{NC} or V _{NO} = 3 V, V _{COM} = 1 V,	Switch OFF, See Figure 14	25°C Full	3.6 V	−0.1	0.05	0.1 0.2	μA
		V _{NC} or V _{NO} = 0 to 3.6 V, V _{COM} = 3.6 V to 0, or V _{NC} or V _{NO} = 3.6 V to 0, V _{COM} = 0 to 3.6 V,	Switch OFF, See Figure 14	25°C Full	0 V	−2	0.05	2 10	
				25°C	3.6 V	−0.1	0.05	0.1	
				Full	0 V	−0.2	0.2		
COM OFF leakage current	I _{COM(OFF)}	V _{COM} = 1 V, V _{NC} or V _{NO} = 3 V, or V _{COM} = 3 V, V _{NC} or V _{NO} = 3 V,	Switch OFF, See Figure 14	25°C Full	3.6 V	−0.1	0.05	0.1 0.2	μA
		V _{COM} = 0 to 3.6 V, V _{NC} or V _{NO} = 3.6 V to 0, or V _{COM} = 3.6 V to 0, V _{NC} or V _{NO} = 0 to 3.6 V,	Switch OFF, See Figure 14	25°C Full	0 V	−2	0.05	2 10	
				25°C	3.6 V	−0.1	0.05	0.1	
				Full	0 V	−0.2	0.2		
NC, NO ON leakage current	I _{NC(ON)} I _{NO(ON)}	V _{NC} or V _{NO} = 1 V, V _{COM} = Open, or V _{NC} or V _{NO} = 3 V, V _{COM} = Open,	Switch ON, See Figure 15	25°C Full	3.6 V	−0.1	0.05	0.1 0.2	μA
				Full	3.6 V	−0.1	0.05	0.1 0.2	
COM ON leakage current	I _{COM(ON)}	V _{COM} = 1 V, V _{NC} or V _{NO} = Open, or V _{COM} = 3 V, V _{NC} or V _{NO} = Open,	Switch ON, See Figure 15	25°C Full	3.6 V	−0.1	0.05	0.1 0.2	μA
				Full	3.6 V	−0.1	0.05	0.1 0.2	
Digital Control Inputs (I _N , $\overline{\text{EN}}$)(2)									
Input logic high	V _{IH}			Full		2		V ₊	V
Input logic low	V _{IL}			Full		0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C	3.6 V	−1	0.05	1	μA
				Full		−1		1	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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Electrical Characteristics for 3.3-V Supply⁽¹⁾ (continued)

$V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{COM} = 2\text{ V}$, $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$, See Figure 17	25°C	3.3 V	2.5	3.5	8	ns
			Full	3 V to 3.6 V	2.5		9	
Turn-off time	t_{OFF}	$V_{COM} = 2\text{ V}$, $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$, See Figure 17	25°C	3.3 V	0.5	2	6.5	ns
			Full	3 V to 3.6 V	0.5		7	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$ $C_L = 0.1\text{ nF}$, See Figure 22	25°C	3.3 V		2		pC
NC, NO OFF capacitance	$C_{NC(OFF)}$ $C_{NO(OFF)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch OFF, See Figure 16	25°C	3.3 V		4.5		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF, See Figure 16	25°C	3.3 V		9		pF
NC, NO ON capacitance	$C_{NC(ON)}$ $C_{NO(ON)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch ON, See Figure 16	25°C	3.3 V		16		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON, See Figure 16	25°C	3.3 V		16		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND, See Figure 16	25°C	3.3 V		3		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch ON, See Figure 18	25°C	3.3 V		300		MHz
OFF isolation	O_{ISO}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch OFF, See Figure 19	25°C	3.3 V		-48		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch ON, See Figure 20	25°C	3.3 V		-48		dB
Crosstalk Adjacent	$X_{TALK(ADJ)}$	$R_L = 50\ \Omega$, $f = 10\text{ MHz}$, Switch ON, See Figure 21	25°C	3.3 V		-81		dB
Total harmonic distortion	THD	$R_L = 600\ \Omega$, $C_L = 50\text{ pF}$, $f = 20\text{ Hz to }20\text{ kHz}$, See Figure 23	25°C	3.3 V		0.21		%
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND, Switch ON or OFF	25°C	3.6 V		2.5	7	μA
			Full				10	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

Electrical Characteristics for 2.5-V Supply⁽¹⁾

$V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T _A	V ₊	MIN	TYP	MAX	UNIT	
Analog Switch										
Analog signal range	V _{COM} , V _{NC} , V _{NO}					0		V ₊	V	
ON-state resistance	r _{on}	0 ≤ (V _{NC} or V _{NO}) ≤ V ₊ , I _{COM} = −24 mA,	Switch ON, See Figure 13	25°C Full	2.3 V	12 22		20	Ω	
ON-state resistance match between channels	Δr _{on}	V _{NC} or V _{NO} = 1.6 V, I _{COM} = −24 mA,	Switch ON, See Figure 13	25°C Full	2.3 V	0.3		1 2	Ω	
ON-state resistance flatness	r _{on(flat)}	0 ≤ (V _{NC} or V _{NO}) ≤ V ₊ , I _{COM} = −24 mA,	Switch ON, See Figure 13	25°C Full	2.3 V	14		18 20	Ω	
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V _{NC} or V _{NO} = 0.5 V, V _{COM} = 2.2 V, or V _{NC} or V _{NO} = 2.2 V, V _{COM} = 0.5 V,	Switch OFF, See Figure 14	25°C Full	2.7 V	−0.1	0.05	0.1 0.2	μA	
		V _{NC} or V _{NO} = 0 to 3.6 V, V _{COM} = 3.6 V to 0, or V _{NC} or V _{NO} = 3.6 V to 0, V _{COM} = 0 to 3.6 V,	Switch OFF, See Figure 14	25°C Full	0 V	−2	0.05	2 10		
COM OFF leakage current	I _{COM(OFF)}	V _{COM} = 0.5 V, V _{NC} or V _{NO} = 2.2 V, or V _{COM} = 2.2 V, V _{NC} or V _{NO} = 0.5 V,	Switch OFF, See Figure 14	25°C Full	2.7 V	−0.1	0.05	0.1 0.2	μA	
		V _{COM} = 0 to 3.6 V, V _{NC} = 3.6 V to 0, or V _{COM} = 3.6 V to 0, V _{NC} = 0 to 3.6 V,	Switch OFF, See Figure 14	25°C Full	0 V	−2	0.05	2 10		
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V _{NC} or V _{NO} = 0.5 V, V _{COM} = Open, or V _{NC} or V _{NO} = 2.2 V, V _{COM} = Open,	Switch ON, See Figure 15	25°C Full	2.7 V	−0.1	0.05	0.1 0.2	μA	
COM ON leakage current	I _{COM(ON)}	V _{COM} = 0.5 V, V _{NC} or V _{NO} = Open, or V _{COM} = 2.2 V, V _{NC} or V _{NO} = Open,	Switch ON, See Figure 15	25°C Full	2.7 V	−0.1	0.05	0.1 0.2	μA	
Digital Control Inputs (I _N , $\overline{\text{EN}}$)(2)										
Input logic high	V _{IH}			Full		1.7		V ₊	V	
Input logic low	V _{IL}			Full		0		0.7	V	
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C	2.7 V	−0.1	0.05	0.1	μA	
				Full		−1		1		

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at V_+ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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Electrical Characteristics for 2.5-V Supply⁽¹⁾ (continued)

$V_+ = 2.3 \text{ V to } 2.7 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic								
Turn-on time	t_{ON}	$V_{COM} = 1.5 \text{ V}$, $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$, See Figure 17	25°C	2.5 V	2.5	5	9.5	ns
			Full	2.3 V to 2.7 V	2.5		10.5	
Turn-off time	t_{OFF}	$V_{COM} = 1.5 \text{ V}$, $R_L = 300 \Omega$, $C_L = 35 \text{ pF}$, See Figure 17	25°C	2.5 V	0.5	3	7.5	ns
			Full	2.3 V to 2.7 V	0.5		9	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$ $C_L = 0.1 \text{ nF}$, See Figure 22	25°C	2.5 V		1		pC
NC, NO OFF capacitance	$C_{NC(OFF)}$ $C_{NO(OFF)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch OFF, See Figure 16	25°C	2.5 V		3		pF
COM OFF capacitance	$C_{COM(OFF)}$	$V_{COM} = V_+$ or GND, Switch OFF, See Figure 16	25°C	2.5 V		9		pF
NC, NO ON capacitance	$C_{NC(ON)}$ $C_{NO(ON)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch ON, See Figure 16	25°C	2.5 V		16		pF
COM ON capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch ON, See Figure 16	25°C	2.5 V		16		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND, See Figure 16	25°C	2.5 V		3		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON, See Figure 18	25°C	2.5 V		300		MHz
OFF isolation	O_{ISO}	$R_L = 50 \Omega$, $f = 10 \text{ MHz}$, Switch OFF, See Figure 19	25°C	2.5 V		-48		dB
Crosstalk	X_{TALK}	$R_L = 50 \Omega$, $f = 10 \text{ MHz}$, Switch ON, See Figure 20	25°C	2.5 V		-48		dB
Crosstalk Adjacent	$X_{TALK(ADJ)}$	$R_L = 50 \Omega$, $f = 10 \text{ MHz}$, Switch ON, See Figure 21	25°C	3.3 V		-81		dB
Total harmonic distortion	THD	$R_L = 600 \Omega$, $C_L = 50 \text{ pF}$, $f = 20 \text{ Hz to } 20 \text{ kHz}$, See Figure 23	25°C	2.5 V		0.33		%
Supply								
Positive supply current	I_+	$V_I = V_+$ or GND, Switch ON or OFF	25°C	2.7 V		2.5	7	μA
			Full				10	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

TYPICAL PERFORMANCE

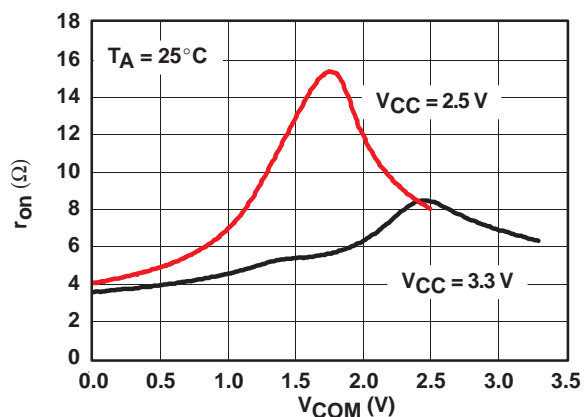


Figure 1. r_{on} vs V_{COM}

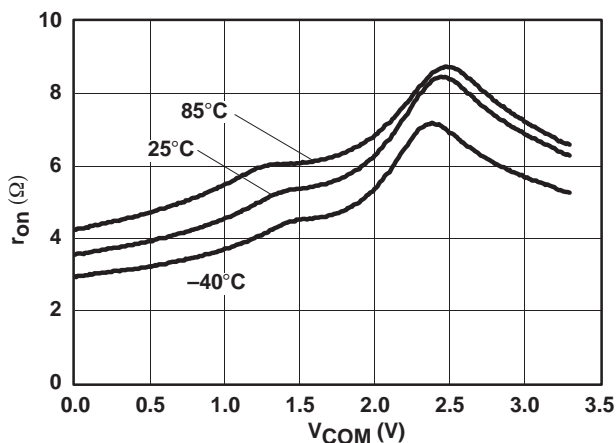


Figure 2. r_{on} vs V_{COM} ($V_+ = 3.3$ V)

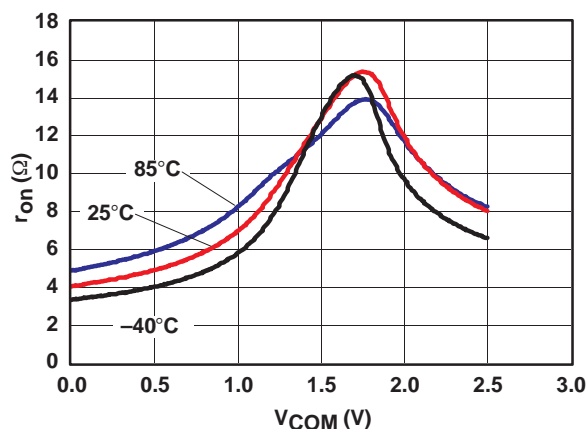


Figure 3. r_{on} vs V_{COM} ($V_+ = 3.3$ V)

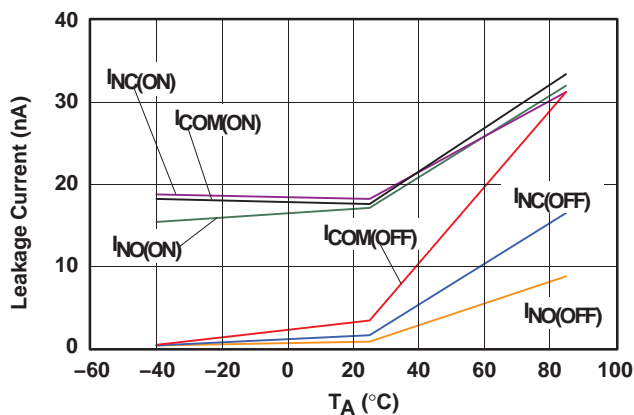


Figure 4. Leakage Current vs Temperature
($V_+ = 3.6$ V)

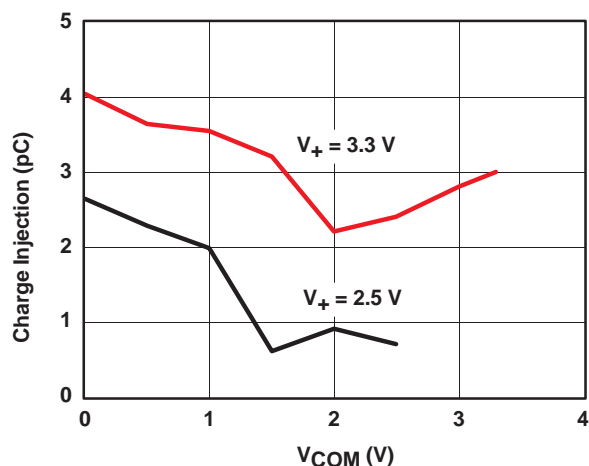


Figure 5. Charge-Injection (Q_C) vs V_{COM}

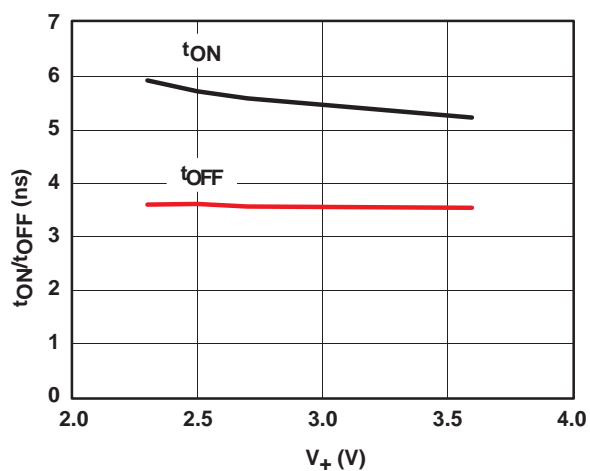


Figure 6. t_{ON} and t_{OFF} vs Supply Voltage

TYPICAL PERFORMANCE

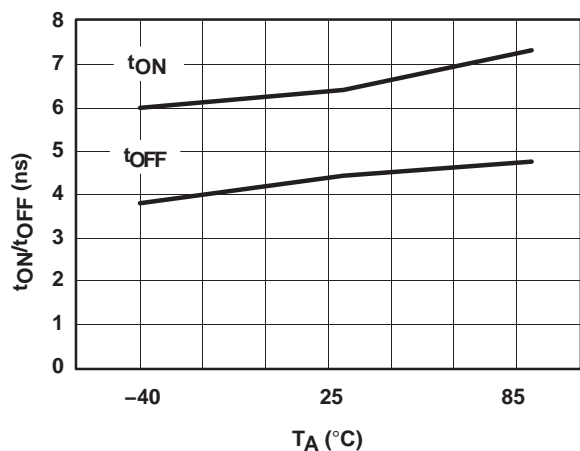


Figure 7. t_{ON} and t_{OFF} vs Temperature ($V_+ = 5$ V)

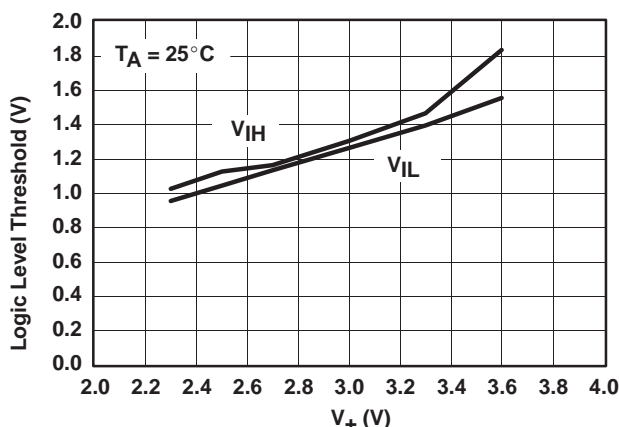


Figure 8. Logic-Level Threshold vs V_+

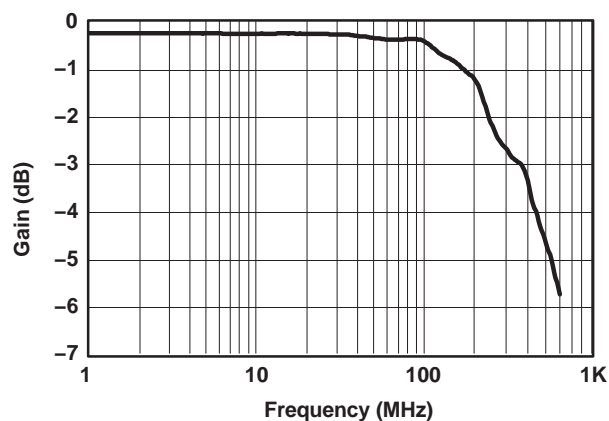


Figure 9. Gain vs Frequency Bandwidth ($V_+ = 3.3$ V)

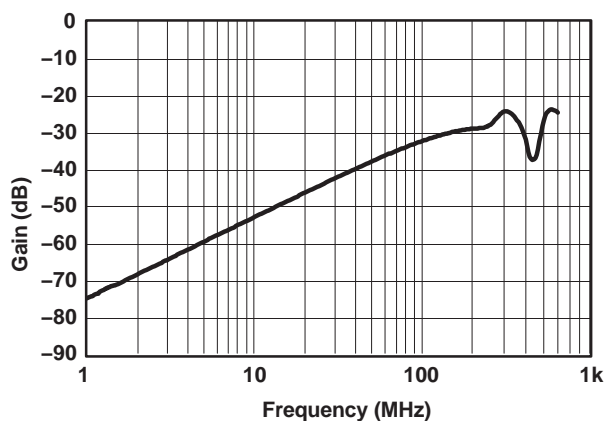


Figure 10. OFF Isolation vs Frequency ($V_+ = 3.3$ V)

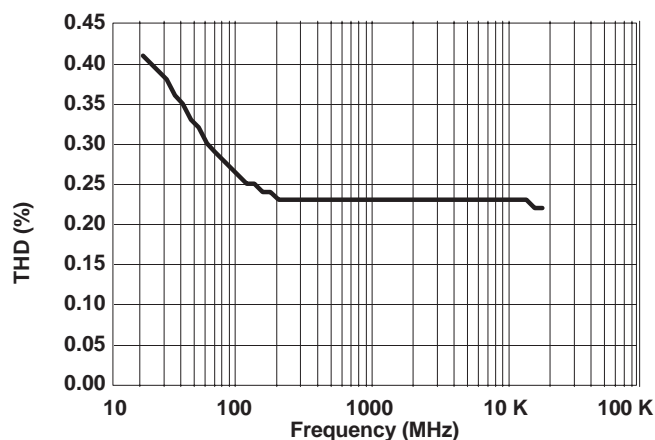


Figure 11. Total Harmonic Distortion vs Frequency

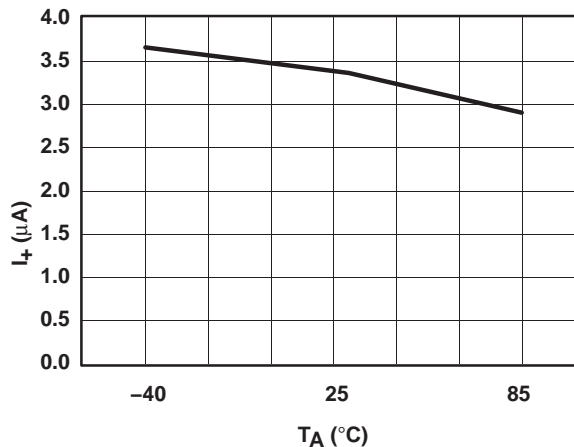


Figure 12. Power-Supply Current vs Temperature ($V_+ = 3.3$ V)

PIN DESCRIPTION

PIN NUMBER	NAME	DESCRIPTION
1	IN	Digital control pin to select between NC and NO
2	NC1	Normally closed
3	NO1	Normally open
4	COM1	Common
5	NC2	Normally closed
6	NO2	Normally open
7	COM2	Common
8	GND	Digital ground
9	COM3	Common
10	NO3	Normally open
11	NC3	Normally closed
12	COM4	Common
13	NO4	Normally open
14	NC4	Normally closed
15	$\overline{\text{EN}}$	Chip Enable (active low)
16	V ₊	Power supply

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
V_{COM}	Voltage at COM
V_{NC}	Voltage at NC
V_{NO}	Voltage at NO
r_{on}	Resistance between COM and NC or NO ports when the channel is ON
Δr_{on}	Difference of r_{on} between channels in a specific device
$r_{on(flat)}$	Difference between the maximum and minimum value of r_{on} in a channel over the specified range of conditions
$I_{NC(OFF)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state
$I_{NC(ON)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open
$I_{NO(OFF)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
$I_{NO(ON)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
$I_{COM(OFF)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NC or NO) in the OFF state
$I_{COM(ON)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NC or NO) in the ON state and the output (NC or NO) open
V_{IH}	Minimum input voltage for logic high for the control input (IN, \overline{EN})
V_{IL}	Maximum input voltage for logic low for the control input (IN, \overline{EN})
V_I	Voltage at the control input (IN, \overline{EN})
I_{IH}, I_{IL}	Leakage current measured at the control input (IN, \overline{EN})
t_{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (NC or NO) signal when the switch is turning ON.
t_{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (NC or NO) signal when the switch is turning OFF.
Q_C	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC or NO) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$, C_L is the load capacitance, and ΔV_{COM} is the change in analog output voltage.
$C_{NC(OFF)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF
$C_{NC(ON)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is ON
$C_{NO(OFF)}$	Capacitance at the NC port when the corresponding channel (NO to COM) is OFF
$C_{NO(ON)}$	Capacitance at the NC port when the corresponding channel (NO to COM) is ON
$C_{COM(OFF)}$	Capacitance at the COM port when the corresponding channel (COM to NC) is OFF
$C_{COM(ON)}$	Capacitance at the COM port when the corresponding channel (COM to NC) is ON
C_I	Capacitance of control input (IN, \overline{EN})
O_{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM) in the OFF state.
X-TALK	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC1 to NO1). Adjacent crosstalk is a measure of unwanted signal coupling from an ON channel to an adjacent ON channel (NC1 to NC2). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is –3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
I_+	Static power-supply current with the control (IN) pin at V_+ or GND

PARAMETER MEASUREMENT INFORMATION

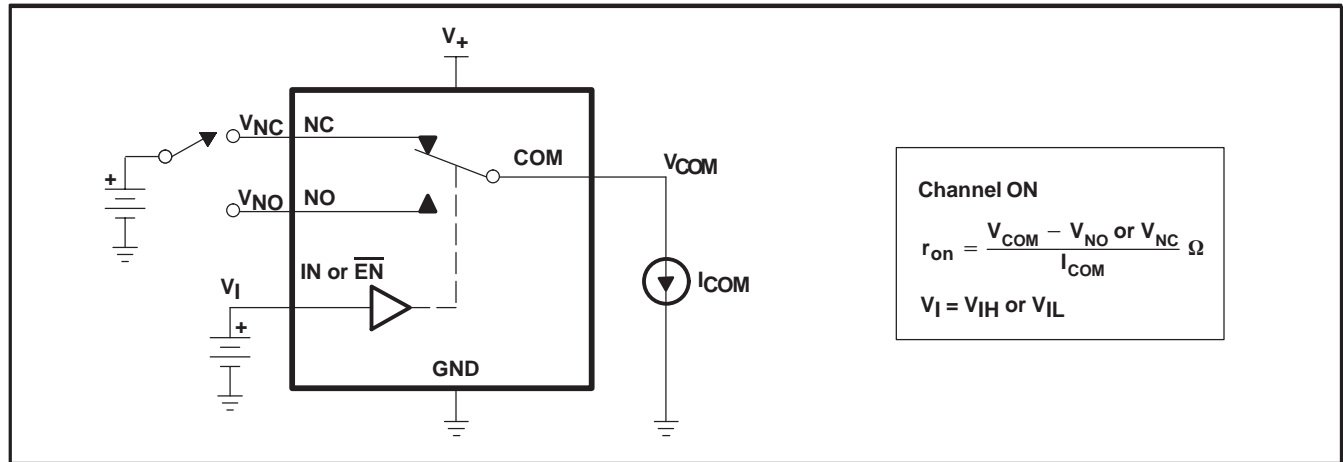


Figure 13. ON-State Resistance (r_{on})

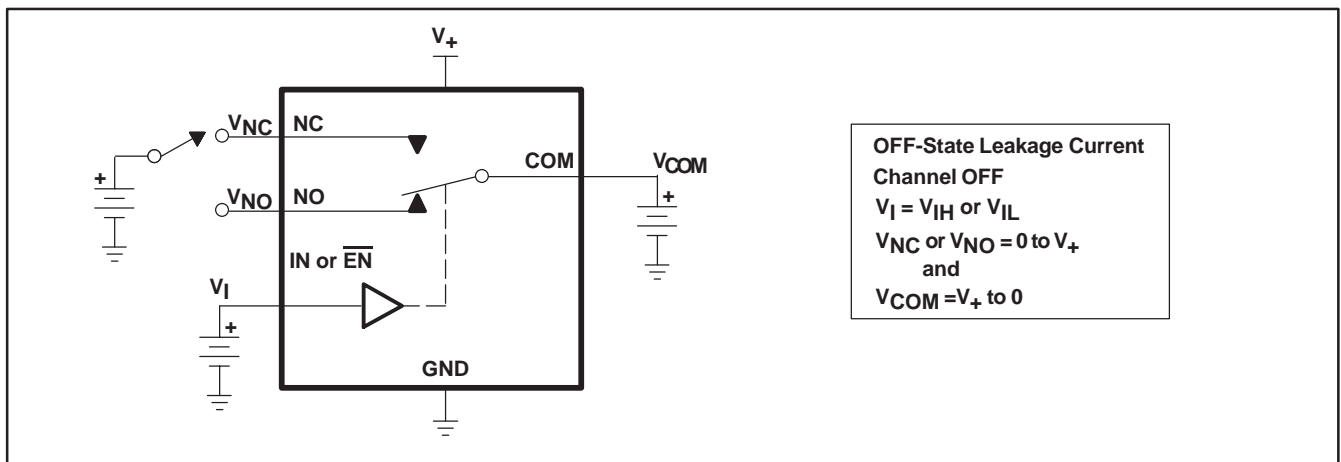


Figure 14. OFF-State Leakage Current ($I_{COM(OFF)}$, $I_{NC(OFF)}$, $I_{NO(OFF)}$)

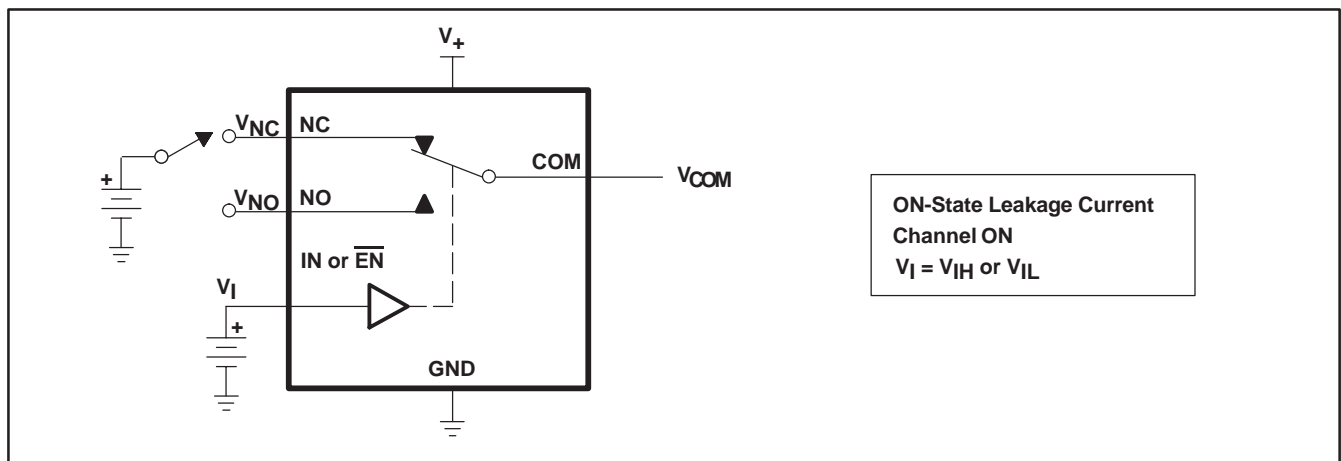


Figure 15. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$)

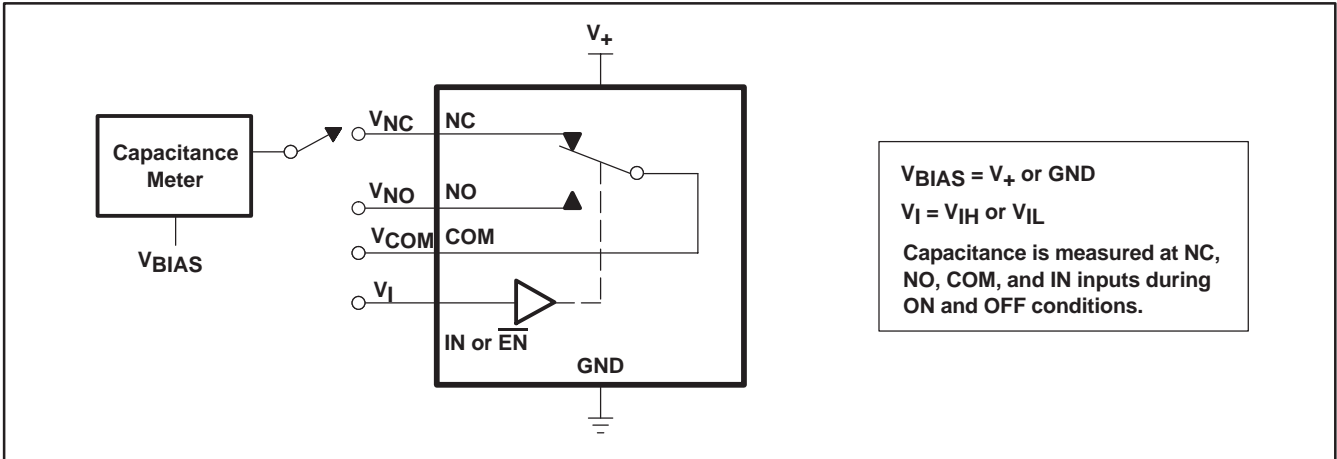
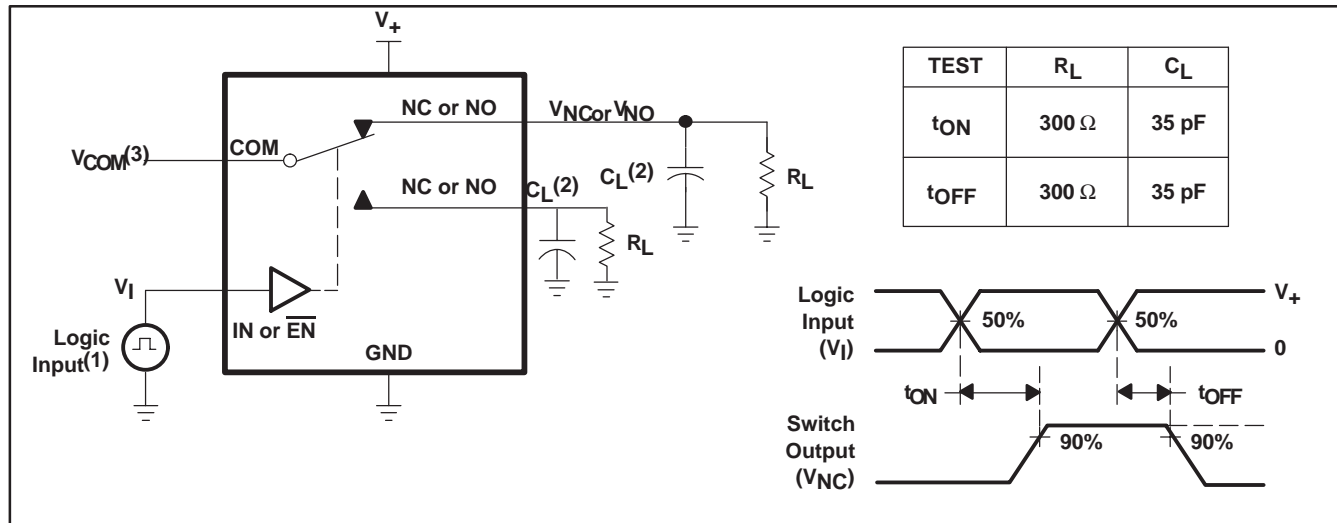


Figure 16. Capacitance (C_I , $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)



- (1) All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.
(2) C_L includes probe and jig capacitance.
(3) See Electrical Characteristics for V_{COM}.

Figure 17. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

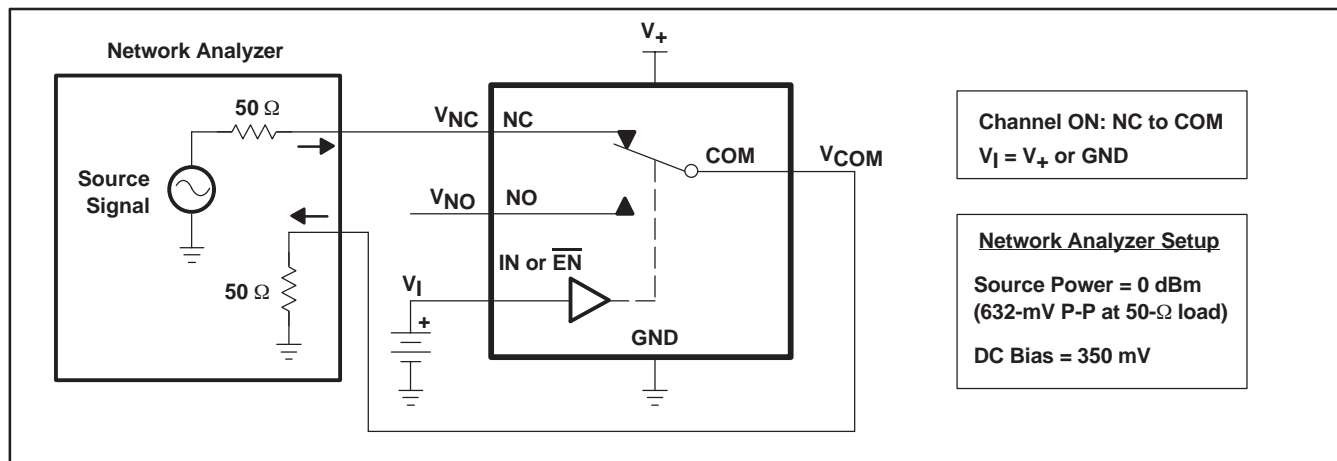


Figure 18. Bandwidth (BW)

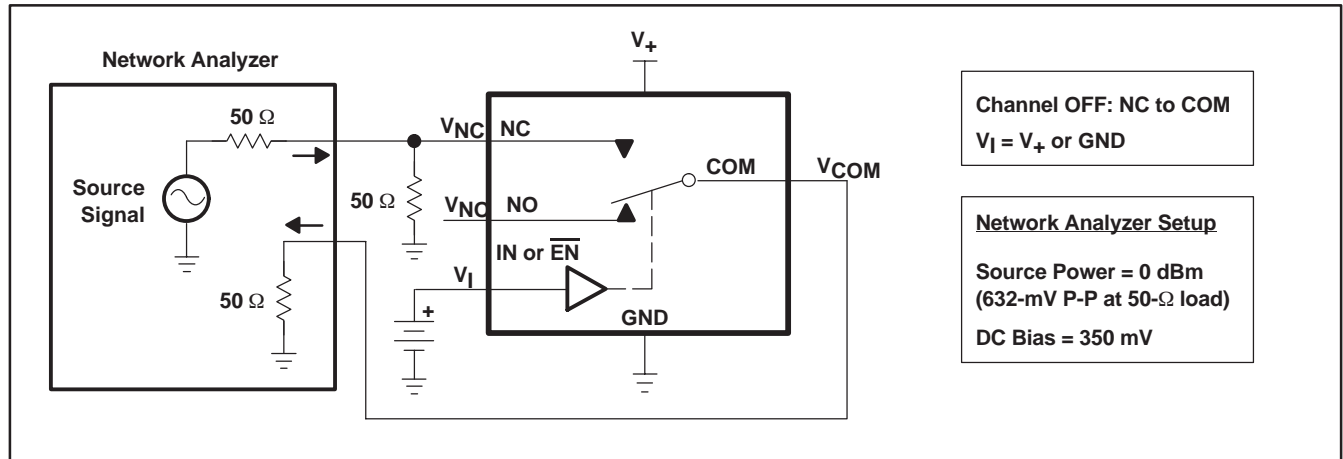


Figure 19. OFF Isolation (O_{ISO})

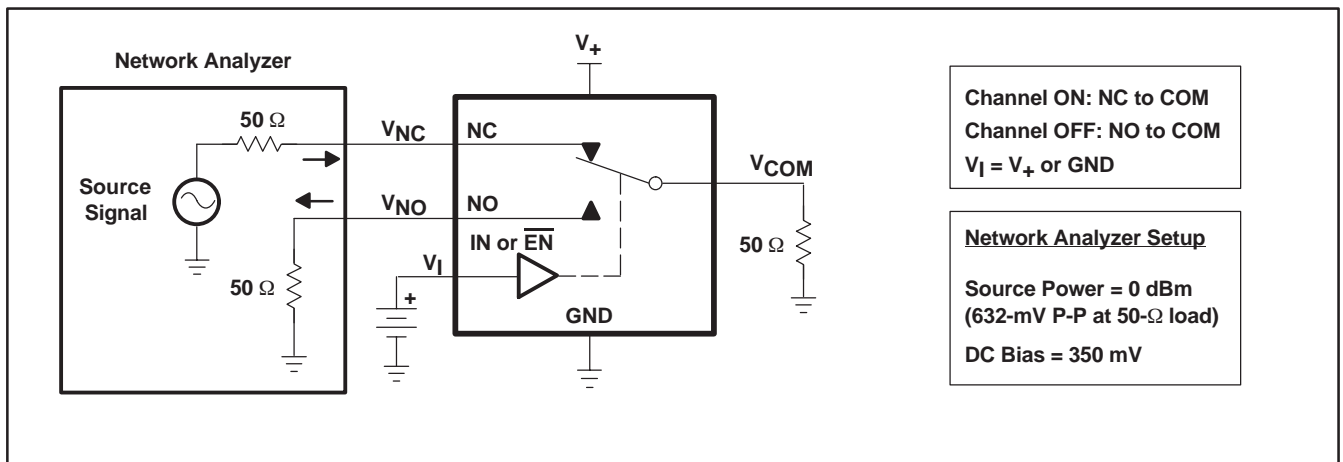


Figure 20. Crosstalk (X_{TALK})

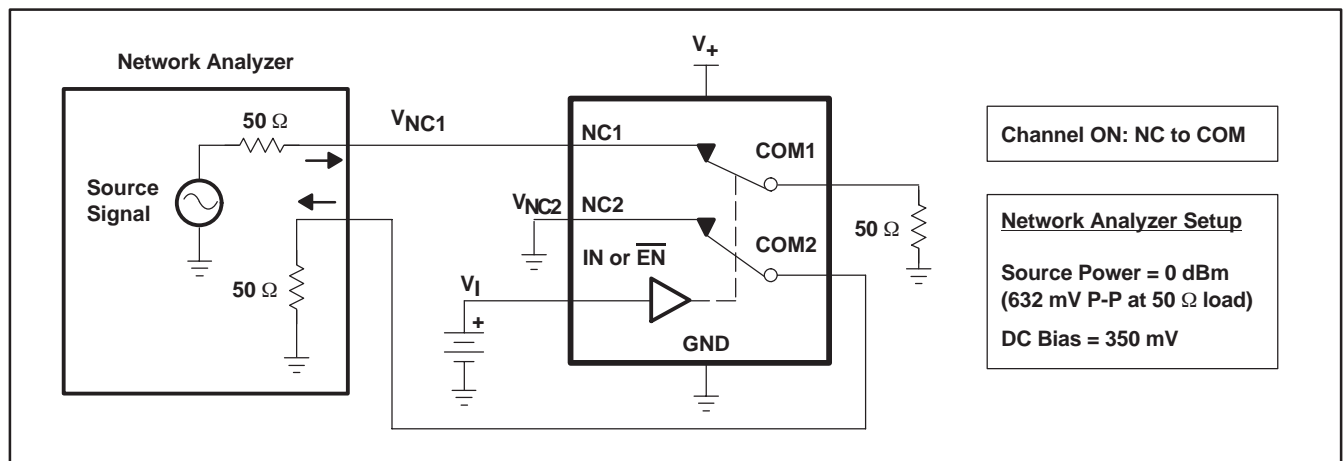
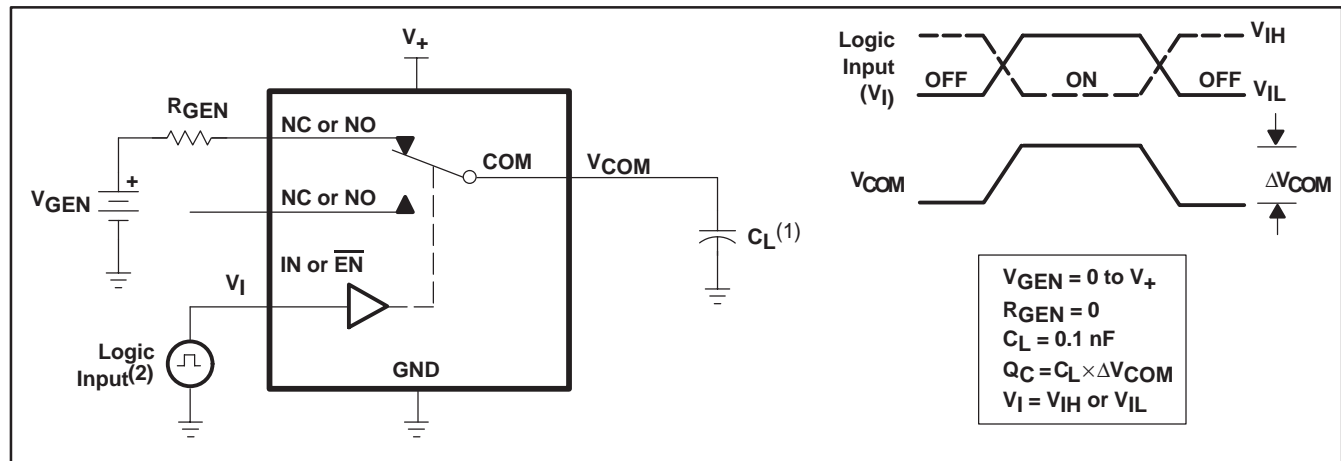


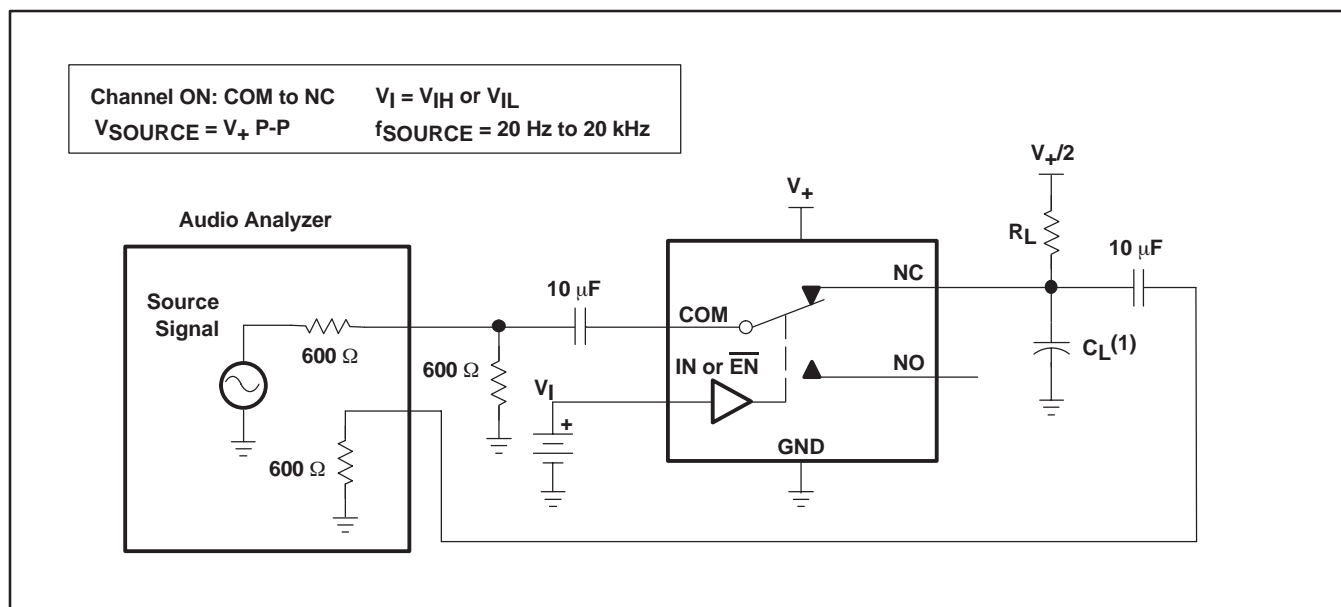
Figure 21. Crosstalk Adjacent



(1) C_L includes probe and jig capacitance.

(2) All input pulses are supplied by generators having the following characteristics: $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.

Figure 22. Charge Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 23. Total Harmonic Distortion (THD)

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TS3A5018D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018DBQR	ACTIVE	SSOP/QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS3A5018DBQRE4	ACTIVE	SSOP/QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS3A5018DBQRG4	ACTIVE	SSOP/QSOP	DBQ	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TS3A5018DE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018DGVR	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018DGVRE4	ACTIVE	TVSOP	DGV	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018DR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018DRE4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018PWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS3A5018RGYR	ACTIVE	QFN	RGY	16	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

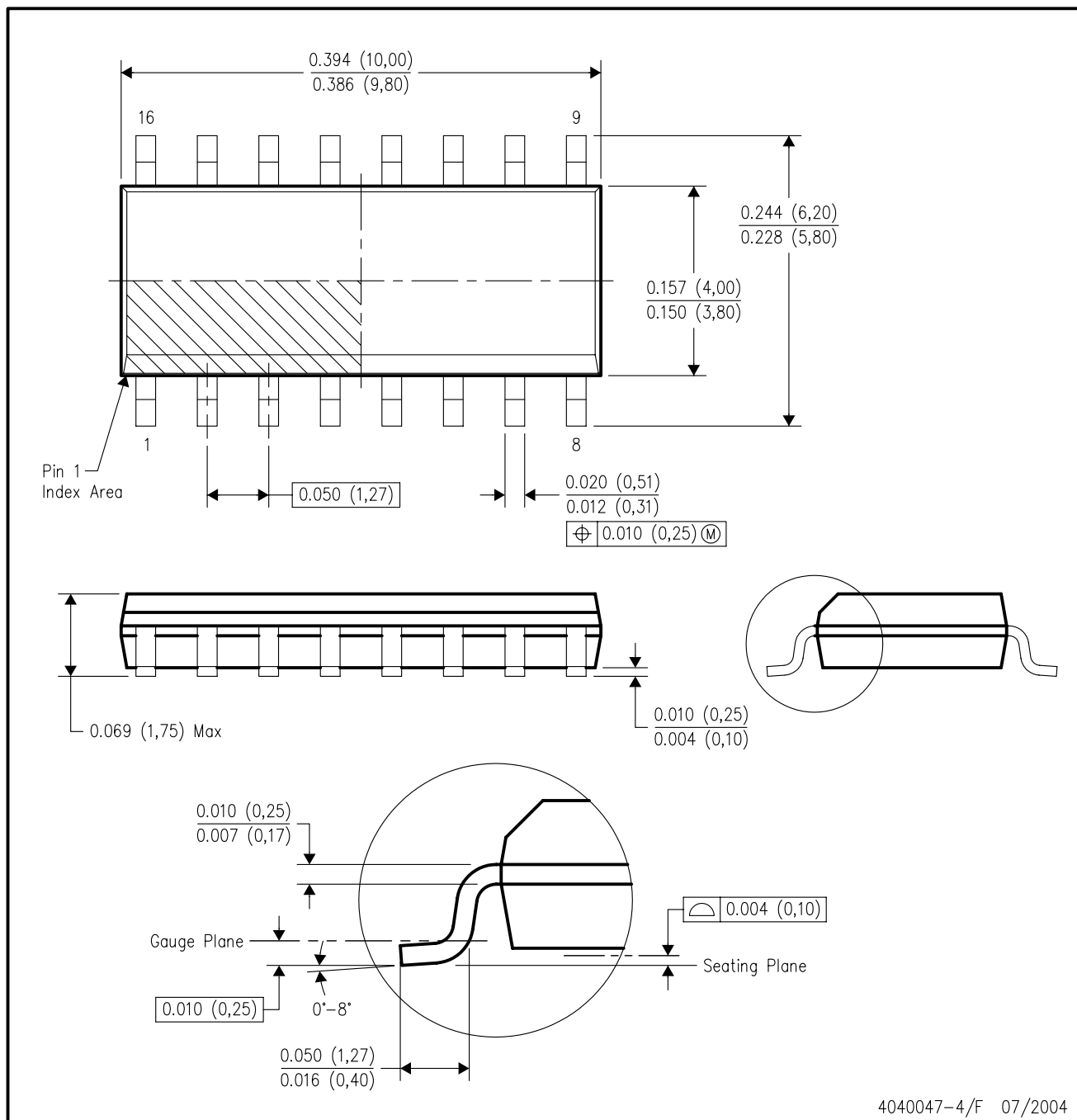
24 PINS SHOWN



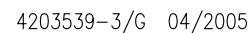
- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194

D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



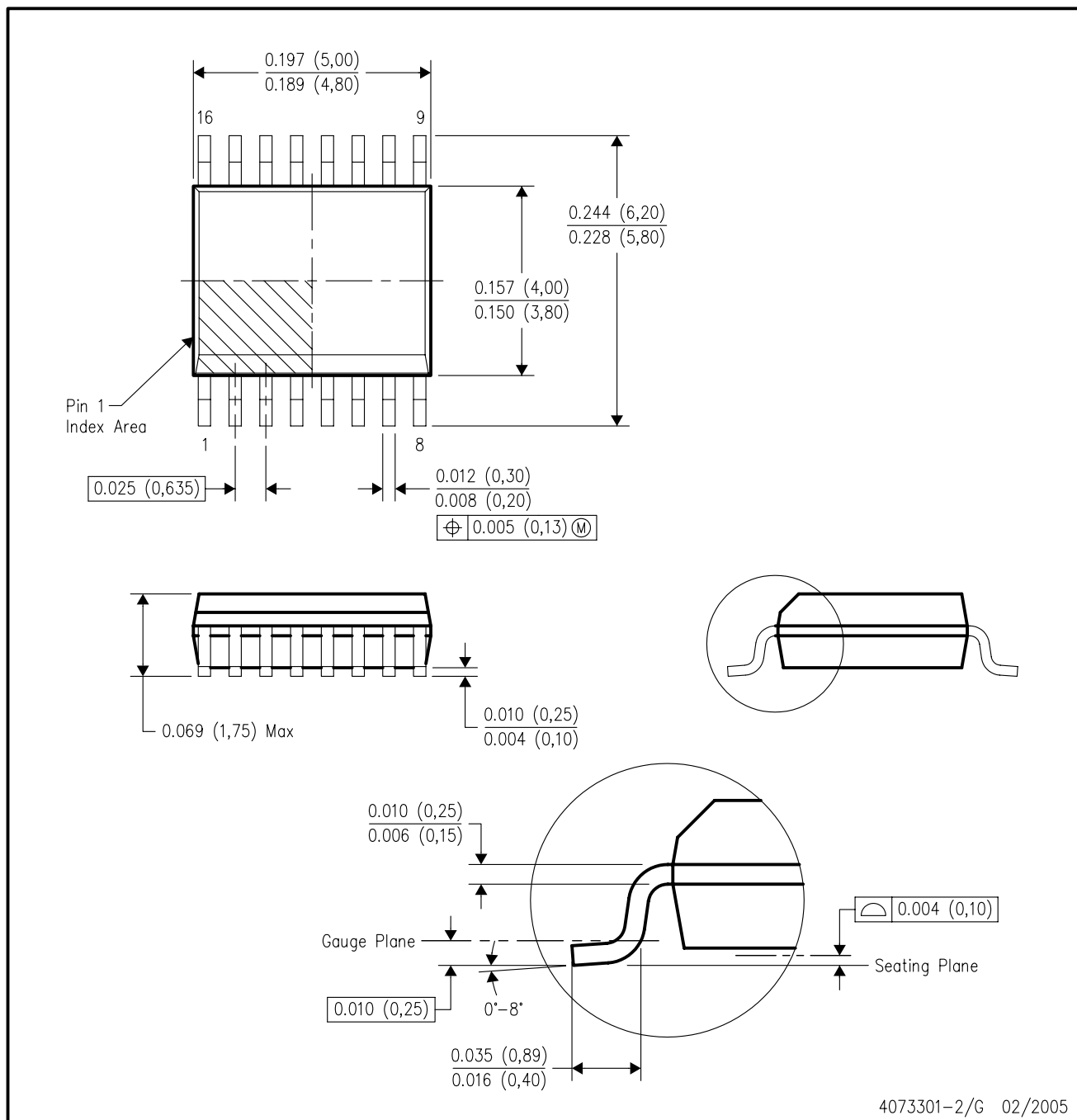
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DBQ (R-PDSO-G16)

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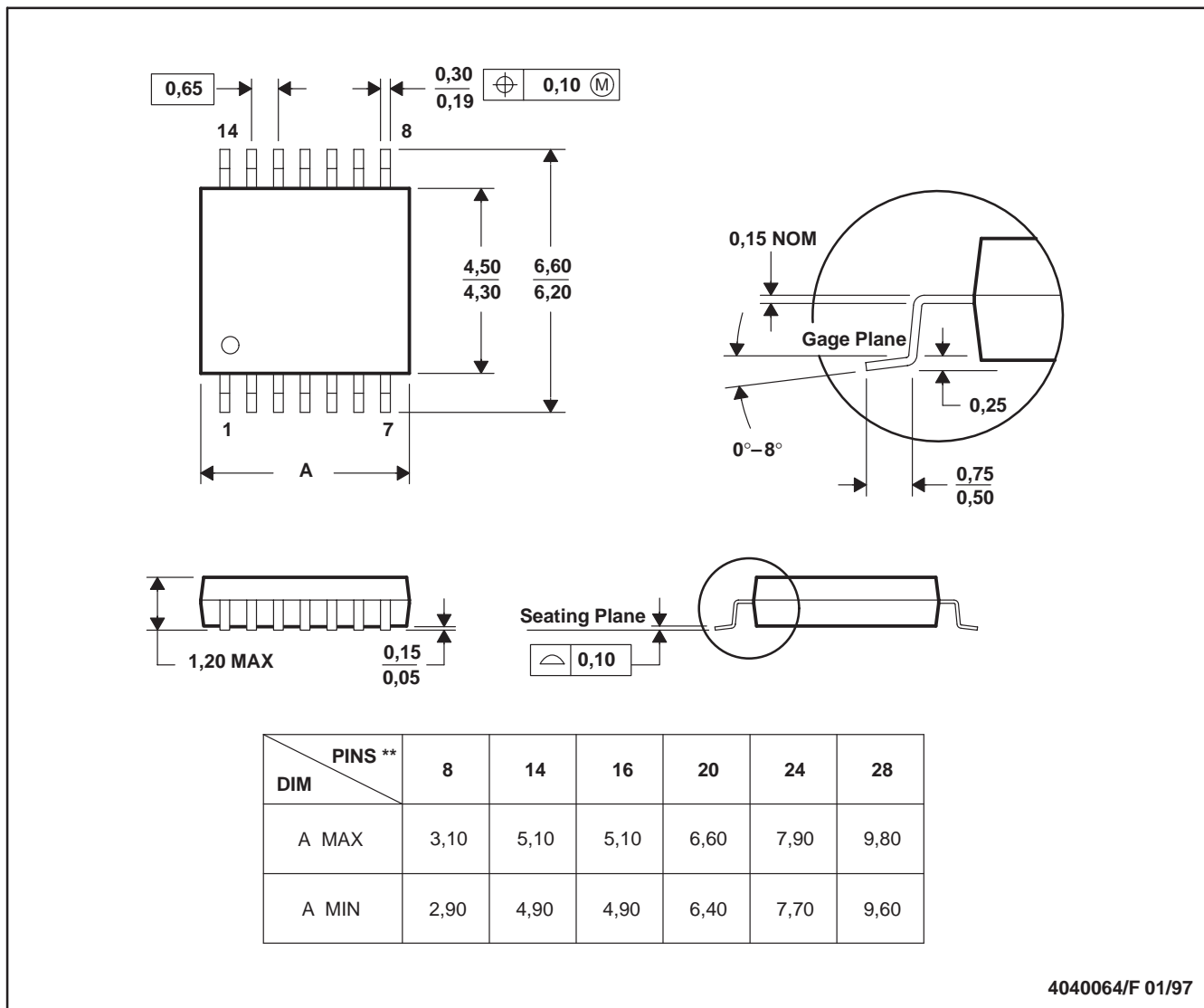


4073301-2/G 02/2005

PW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



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